CPH5524

ON Semiconductor®

http://onsemi.com

Bipolar Transistor

(-)50V, (-)6A, Low VCE(sat) Complementary Dual CPH5

Applications

· Relay drivers, lamp drivers, motor drivers, IGBT gate drivers

Features

- · Composite type with a PNP transistor and an NPN transistor contained in one package, facilitating high-density mounting
- · Ultrasmall package facilitate miniaturization in end products. (0.9mm mounting height)

Specifications (): PNP

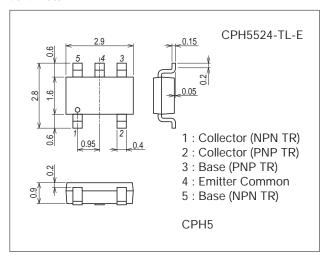
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-50)100	V
Collector-to-Emitter Voltage	VCEO		(-)50	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	IC		(-)3	Α
Collector Current (Pulse)	ICP		(–)6	А
Base Current	ΙΒ		(-)600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm) 1unit	0.9	W
Total Power Dissipation	PT	Mounted on a ceramic board (600mm ² ×0.8mm)	1.2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit: mm (typ) 7017A-009

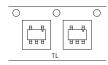


Product & Package Information

• Package : CPH5

• JEITA, JEDEC : SC-74A, SOT-25 • Minimum Packing Quantity : 3,000 pcs./reel

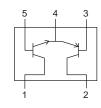
Packing Type: TL



Marking



Electrical Connection

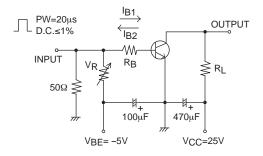


September, 2013

Electrical Characteristics at Ta=25°C

Parameter	Cumbal	Conditions	Ratings			- Unit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0A			(-)1	μΑ	
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0A			(-)1	μΑ	
DC Current Gain	hFE	V _{CE} =(-)2V, I _C =(-)100mA	200		560		
Gain-Bandwidth Product	fŢ	V _{CE} =(-)10V, I _C =(-)500mA		(390)380		MHz	
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(24)13		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)1	I _C =(-)1A, I _B =(-)50mA		(-115)	(-230)	mV	
				90	130	mV	
	V _{CE} (sat)2	I _C =(-)2A, I _B =(-)100mA		(-240)	(-650)	mV	
				160	240	mV	
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=(-)2A, IB=(-)100mA		(-)0.88	(-)1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μA, I _E =0A	(-50)100			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(-)1mA, R _{BE} =∞	(-)50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)10μA, I _C =0A	(-)6			V	
Turn-On Time	ton			(30)35		ns	
Storage Time	t _{stg}	See specified Test Circuit.		(230)300		ns	
Fall Time	t _f			(18)25		ns	

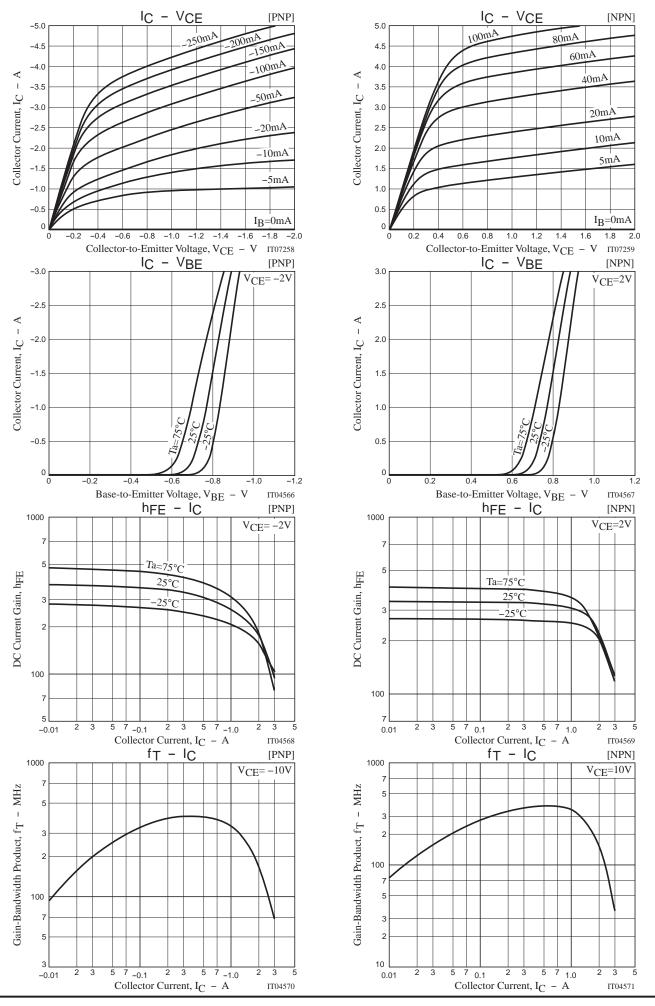
Switching Time Test Circuit

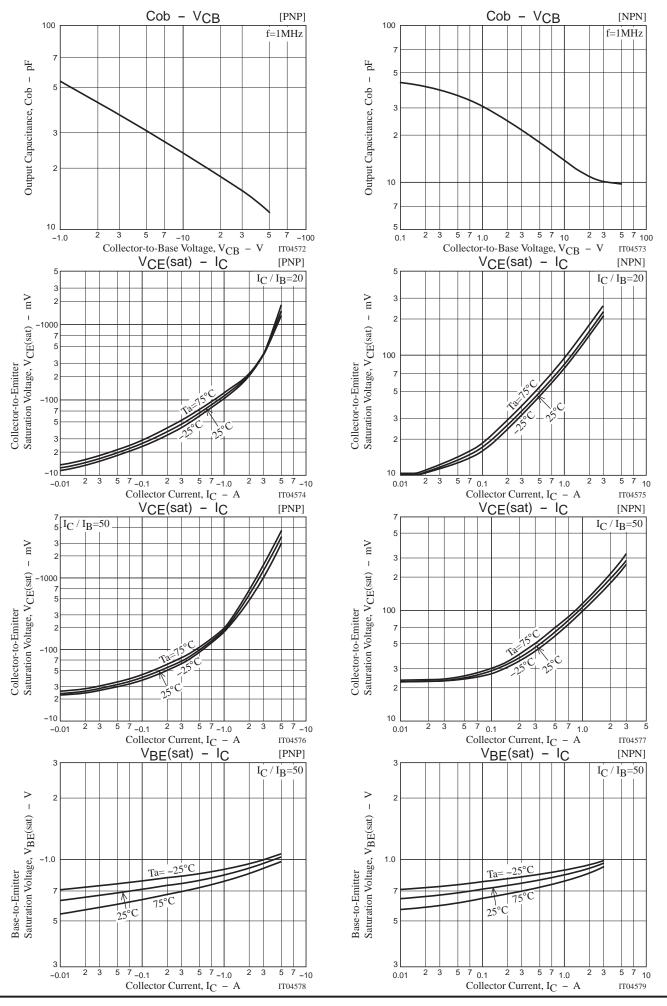


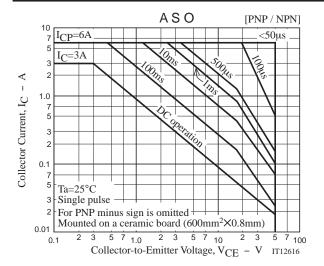
 $I_{C} = 10I_{B1} = -10I_{B2} = 1A$ For PNP, the polarity is reversed.

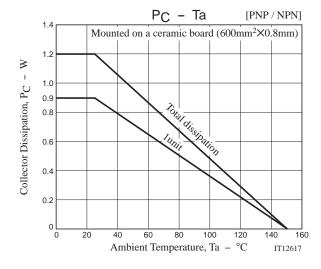
Ordering Information

Device	Package	Shipping	memo	
CPH5524-TL-E	PH5524-TL-E CPH5		Pb Free	







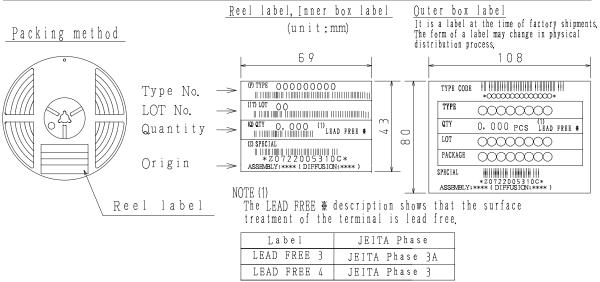


Embossed Taping Specification

CPH5524-TL-E

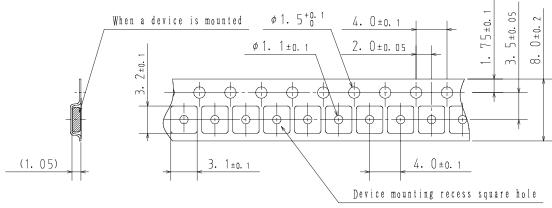
1. Packing Format

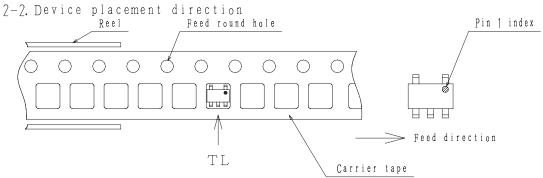
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner $BOX(C-1)$	Outer BOX (A-7)
CPH5	СРН6	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210



7. Taping configuration

2-1. Carrier tape size (unit:mm)





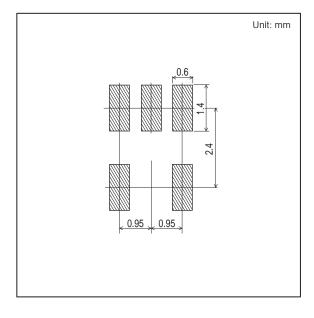
Those with pin 1 index on the feed hole side · · · · · TL

Outline Drawing

CPH5524-TL-E

Mass (g) Unit 0.02 * For reference mm 0. 15^{+0. 1}_{-0. 05} 2. 9±0. 1 0.6±0.1 0. 2±0.1 *1 | *1 O. 05±0.05 2. 8±0. 15 1.6±0.1 *1 0.6±0.1 0.95 PIN#1 0.9±0.05 0.05 \$ *1:Lot indication

Land Pattern Example



ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equa

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: CPH5524-TL-E